Quantum Gunn e ect: Zero-resistance state in 2D electron gas.

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U sually, the conductivity is quantized as the inverse of the resistivity, $= hc=ie^2$, $= ie^2=hc$, and the velocity versus the electric eld is linear, v = E, where is the m obility of the electrons. How ever, when the applied electric eld exceeds a certain value, m icrow aves are em itted and the relation v = E breaks down so that the velocity actually reduces as E increases. In this region, when m agnetic eld is applied, the conductivity quantizes like the m agnetic eld, i.e., in multiples of hc=e which is di erent from the usual quantization. Because of the ux quantization, the resistivity will touch zero in the region of high electric eld. Factors like 4/5 arise due to new spin dependence of the e ective charge.

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1. Introduction

Recently, M ani et al¹ have measured the resistivity of G aA s/A IG aA s which is linear at sm all magnetic elds and show s de H aas-van A lphen oscillations for elds larger than $(4/5)B_f$ where $eB_f = m c = !_c$ is the cyclotron frequency. W hen the sam ple is irradiated with m icrow aves of frequency 103 G H z, the linear resistivity below the eld of $(4/5)B_f$ com es down and touches the zero value. W e wish to understand this reduction in the resistivity and why it approaches zero value. Zudov et al² also found that the diagonal resistivity touches the zero value when sam ple is irradiated with m icrow aves of frequency

57 G H z. We have reported³ that spin determ ines the fraction which appears before the magnetic eld, B_f and ux quantization is important to get zero resistivity. Volkov⁴ and B ergeret et al⁵ nd that G unn e ect is important to obtain negative resistivity which is the cause of reduction with respect to the value without the microwave radiation and this type of negative resistance is in agreement with the experimental work of W illett⁶ where observation of the negative resistance was mentioned.

At small electric elds, the velocity is linearly related to the electric eld, v = E. However, at large elds, the velocity does not increase with increasing eld but it decreases. In this region, it is interesting to quantize the conductivity. Since the system radiates m icrowaves, it is called the Gunn electr. The quantization of the magnetic eld in the region of Gunn electric eldads to quantized conductivity. Thus, we report the \quantum Gunn electric (QGE) which is the quantized conductivity in the region of electric eld relevant to Gunn electr. U sually, the conductivity is quantized in units of electric but in the present case, it is quantized in units of hc/e with a suitable multiplier so that the units are correct. Another aspect of the QGE is that as n is varied, several microwave frequencies are emitted instead of only one frequency of the Gunn e ect.

2. Theory

U sually the conductivity, , is de ned by, j = E where j is the electrical current and E is the electric eld. The current is de ned in terms of velocity, v = E where is called the mobility. The electron as well as the hole currents can thus be written in terms of velocity as,

$$= n_i ev_e + n_h ev_h = n_i e_i E + n_h e_h E$$
(1)

This means that v is a linear function of E. Actually, at large electric elds, v as a function of E œases to be linear and when there is su cient heating, energy is emitted in the form of microwaves. Such an emission of microwaves for electric elds larger than a certain characteristic value, E_o is called the G unn e ect. For $E > E_o$, the velocity actually decreases with increasing E. Therefore, the region, $E > E_o$, o ers an unusual opportunity to investigate the ux quantization. The usual quantization of resistivity or that of conductivity, is based on the region $E < E_o$, where $= h = ie^2$ or $= ie^2 = h$. We therefore expect a new type of quantization for elds $E > E_o$. The number of particles with velocity into electric eld requires the know ledge of linearity between the velocity and the electric eld. For $E > E_o$, such a linear form ula is not valid. Therefore, we use a simple form which has a peak at E_o . For $E < E_o$, this function has a linear region so that velocity increases with increasing electric eld up to $E = E_o$. O noe $E > E_o$, the linear behavior is not needed and the system emits microwaves. Therefore, the distribution should have a peak at E_o and should fall for $E > E_o$. Therefore we use,

$$v = E \frac{2}{(E E_{o})^{2} + 2}$$
 (2)

instead of v = $E \cdot At E = E_{o}$, there is a peak in the velocity. For $E < E_{o}$, the velocity becomes,

$$v = E \frac{2}{E_{0}^{2} + 2}$$
(3)

which is linear in E but is smaller than E. At the peak $E = E_o, v = E$ is established and for $E > E_o, v = E [2 = (E^2 + 2)]$ which falls with increasing E. This is the region where G unn e ect is known to occur. W hen the distribution of velocity as a function of electric eld (2) is used the current becomes,

$$j = n_i e_i E_{-i} \frac{2}{(E - E_o)^2 + 2} + n_h e_h E_{-i} \frac{2}{(E - E_o)^2 + 2}$$
 (4)

where $n_i(n_h)$ are the electron (hole) concentrations and $_i$ and $_h$ are the electron and hole m obilities, respectively. The conductivity is determined by two terms, one due to electrons, $_e$ and the other due to holes, $_h$, with,

$$e = n_{i}e_{i}^{2}\left[\frac{1}{(E - E_{o})^{2} + 2} - \frac{2E(E - E_{o})}{f(E - E_{o})^{2} + 2g^{2}}\right] + e_{i}^{2}\frac{dn_{i}}{dE}\frac{E}{(E - E_{o})^{2} + 2g^{2}}$$
(5)

and

$${}_{h} = n_{h}e_{h} {}^{2}\left[\frac{1}{(E E_{o})^{2} + {}^{2}} - \frac{2E(E E_{o})}{f(E E_{o})^{2} + {}^{2}g^{2}}\right] + {}_{h}e^{-2}\frac{dn_{h}}{dE}\frac{E}{(E E_{o})^{2} + {}^{2}}$$
(6)

W hen the electric eld is increased, if the electron concentration increases, that of the holes must reduce so that,

$$\frac{dn_{e}}{dE} = -\frac{dn_{h}}{dE}$$
(7)

Substituting this result in (5) and (6) and adding the two terms,

$$= _{e} + _{h} = _{o} + (_{i} _{h})e^{-2}\frac{dn_{i}}{dE}\frac{E}{(E - E_{o})^{2} + ^{-2}}$$
(8)

where

$$_{\circ} = e^{-2} (n_{i i} + n_{h h}) \left[\frac{1}{(E - E_{\circ})^{2} + 2} - \frac{2E (E - E_{\circ})}{f (E - E_{\circ})^{2} + 2g^{2}} \right]:$$
(9)

In the Gunne ect, m icrow aves are emitted once the applied electric eld is larger than $E_{\rm f}$ but there is no need of any m agnetic eld. There are m any calculations of the application of crossed electric and m agnetic elds to the sem iconductors but in the present problem, v = E has been avoided and peaked distribution has been used so that it will be of interest to see the electron of magnetic eld when $E > E_{\rm f}$. We can apply the m agnetic eld by considering the Lorentz force so that the electric eld becomes,

$$E^{0} = E + \frac{1}{c} (v \quad B):$$
 (10)

In the present case v is a peaked function so that the electric eld becomes,

$$E^{0} = E + \frac{1}{c} (E' - B') \frac{2}{(E - E_{o})^{2} + 2}$$
 (11)

where is the mobility. The e ective electric eld then becomes,

$$E^{0} = \frac{1}{2} j \left[1 + \frac{1}{c} \frac{^{2}B}{(E - E_{o})^{2} + ^{2}} \right]$$
(12)

The second negative term of (9), upon the application of magnetic eld to electrons becomes,

$$\circ ' \frac{2e^{-2}n_{i} \cdot \underline{f} \cdot \underline{f}}{f(E - E_{\circ})^{2} + {}^{2}g^{2}} [1 + \frac{1}{c} \frac{i}{(E - E_{\circ})^{2} + {}^{2}}] [1 - \frac{E_{\circ}}{\underline{f} \cdot \underline{f}}]$$
(13)

which shows that when the applied eld is larger than certain value, the conductivity can reduce. We can write the above conductivity as,

 $_{\circ}$ ' $a_1 [1 + a_2 B]$ (14)

W here we consider the ux quantization, so that the magnetic eld in the area A can be written as $B A = n_{o}$ where $_{o} = hc/e$ which means that the conductivity in the G unn region becomes,

$$a_{1} [1 + a_{2} n_{o} = A]' = a_{1} [1 + a_{2} (n = A)hc = e]$$
(15)

This form ula is very di erent from the $i\hat{e}=h$ type quantization of conductivity but this is a \quantized G unn e ect". W ithout the quantization, where only a single frequency m icrowave was em itted, now m any m ore m icrowave frequencies will be em itted due to di erent values of n in (15). However, the expression (13) is quite approximate so that actual behaviour is much more complicated than by only one term in (15).

Thus we learn that conductivity has positive term s and electric eld dependent negative term s so that when the electric eld is increased the negative term in the conductivity can become large so that conductivity reduces. Thereafter, upon application of magnetic

eld, plateaus can arise due to $\$ ux quantization" This conductivity quantization is di erent from the usual quantization in terms of $i\hat{e}=h$. For di erent values of the integer several plateaus can arise which m eans that instead of a single m icrow ave frequency em ission in the G unn e ect, several frequencies can arise. These predicted features of the conductivity are qualitatively in accord with the present day experim ental data. The prediction of em ission of multiple frequencies in the G unn e ect has not yet been varied by the experiments. However, such multiple frequencies in the G unn e ect must occur. The ux quantization measures the product of the charge and the magnetic eld. Therefore, fractional numbers arise in the product eB. These fractions are well predicted in a previous paper³ where it was found that the ux quantization depends on spin. 3. D iscussion s.

Anderson and Brinkm an⁷ have pointed out the importance of observation of zero resistivity when the sample is irradiated with microwaves at a frequency somewhat higher than the cyclotron frequency. They have suggested that it depends on the structure of the energy levels in crossed electric and magnetic elds. The old calculations of the crossed electric and magnetic elds have positive resistance. We have found that the factors like 4/5 arise only when spin is involved due to the spin dependent ux quantization. The resistivity is zero for the ux-quantized state. The negative resistance arises due to heating of the sample above an electric eld of E_0 . This negative resistance phenom enon is called the G unn electric microwaves are emitted by the same. The emission of radiation is associated with negative resistance with absorption associated with positive resistance. The microwave frequency some what higher than the cyclotron frequency is thought to be due to scattering by in purities by the Yale group⁸. However, there is no need of in purities in our calculation and we obtain the correct values without in purities in the pure sample^{9;10}.

Cherem $isin^{11}$ has correctly pointed out that $j = {}_{xy}E$ is violated. In the N shaped current (voltage) characteristics, if peak occurs for negative E, then it serves not much purpose. Sim ilarly, in the S-shaped I(V) characteristics there is no peak for positive electric eld. We need a peak in the current (voltage) characteristics for positive value of the electric eld as we have introduced by eq.(2). In this case G unn electric bads to

reduced or negative resistivity needed by the experiment. Similarly, Shi and X ie¹² used the current linear in E_{\circ} along with integral of current-current correlations. This will not produce a G unne ect which we obtain because of peaked relationship between velocity and the electric eld.

W hen m icrow aves are em itted by the G unn e $\operatorname{ect}^{3} \operatorname{^{18}}$, it is in portant that G oldstone theorem is obeyed. That m eans that G oldstone bosons are em itted. These G oldstone bosons are the heat waves or phonons. The em ission of phonons must be accompanied by charge-density waves. This can be seen, for example, by factorizing the electron-phonon interaction. M aking factors of electron number density automatically produces soft phonons. Therefore, there are charge density waves which actually em it electrom agnetic waves or m icrow aves which is another way of saying that there is G unn e ect which leads to negative or reduced resistance. W e can obtain zero resistance by having spin singlets as in superconductivity or triplet states as in ³H e. The charge density waves are param agnetic and hence have sm all resistance. W hen energy is em itted, we call it \negative resistance". In the present phenom enon, there are spin singlets with one component leading to zero resistance accompanied by ux quantization.

4. Conclusions.

We propose a ux-quantized G unne ect as the interpretation of negative resistance which also has plateaus. The fractions before the cyclotron frequency arise due to \spin-dependent ux quantization". The zero-resistance plateaus are due to ux quantization. The zero as well as negative resistance thus is well understood. There is a striking sim - ilarity between the resistance in the present sam ples and the diagonal resistance in the quantum Halle ect. In fact, in the correct theory⁹ which produces the sam e fractional charges as the experimental data, the requirement of the Hall geometry is not strictly needed. The fractional charges, such as 4/3, found in the data are the sam e as in the calculated tables. As far as the emission of microwaves is concerned, more than one frequency will be generated due to integer, n in n_o which quantizes the magnetic eld.

5. R eferences

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